## NSN 5961-01-198-1910

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#### **Inclosure Material:**

Metal

**Overall Length:** 

1.573 inches

#### **Overall Height:**

0.328 inches

#### **Overall Width:**

1.050 inches

#### **Mounting Facility Quantity:**

2

#### **Internal Configuration:**

Junction contact-darlington connected

#### Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-3

#### **Mounting Method:**

Unthreaded hole

### **Features Provided:**

Hermetically sealed case

#### **Semiconductor Material:**

Silicon

#### Voltage Rating In Volts Per Characteristic:

80.0 collector to base voltage/static/emitter open and 7.0 emitter to base voltage, static, collector open and 80.0 collector to emitter voltage/static/base open

#### **Current Rating Per Characteristic:**

20.00 amperes source cutoff current

#### **Power Rating Per Characteristic:**

175.0 watts small-signal input power, common-collector preset

#### Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

#### **Special Features:**

Junction pattern arrangement: npn

#### **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

#### **Terminal Type And Quantity:**

2 pin and 1 case

**Specification Data:** 

81349-mil-s-19500/504 government specification

#### Shelf Life:

N/a

#### Unit Of Measure:

- **Demilitarization:**

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